NSN 5961-00-465-4768

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-465-4768 **Inclosure Material:** Metal **Overall Length:** 0.328 inches **Overall Diameter:** 0.875 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 breakdown voltage, collector-to-emitter, base open and 400.0 breakdown voltage, collector-to-base, emitter open and 5.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 3.50 amperes source cutoff current and 2.00 amperes source cutoff current minor **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No